

RoHS

COMPLIANT

HALOGEN

FREE

Vishay Siliconix

1.0 pC Charge Injection, 100 pA Leakage, 4-Channel Multiplexer

DESCRIPTION

The DG604 is an analog 4-channel CMOS, multiplexer, designed to operate from a + 2.7 V to + 12 V single supply or from \pm 2.7 V to \pm 5 V, dual supplies. The DG604 is fully specified at + 3 V, + 5 V and \pm 5 V. All control logic inputs have guaranteed 2 V logic high limits when operating from + 5 V or \pm 5 V supplies and 1.4 V when operating from a 3 V supply. The DG604 switches conduct equally well in both directions and offer rail to rail analog signal handling. < 1 pC low charge injection, coupled with very low switch capacitance and leakage current makes this product ideal for use in precision instrumentation applications. Operating temperature range is specified from - 40 °C to + 125 °C. The DG604 is available in 14 lead TSSOP and the space saving 1.8 mm x 2.6 mm miniQFN package.

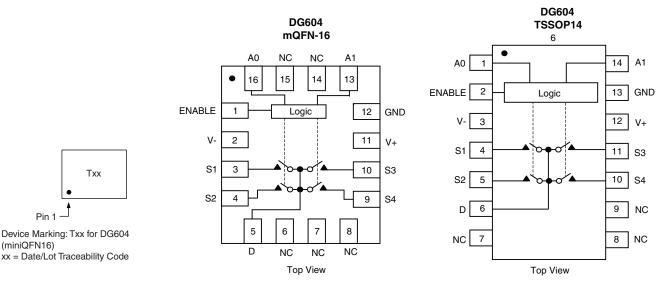
FEATURES

- Halogen-free according to IEC 61249-2-21
 Definition
- Ultra low charge injection (± 1 pC, typ. over the full analog signal range)
- Leakage current < 0.5 nA max. at 85 °C (for DG604EQ-T1-E3)
- Low switch capacitance (C_{soff}, 3 pF typ.)
- Low $R_{DS(on)}$ 115 Ω max.
- Fully specified with single supply operation at 3 V, 5 V and dual supplies at \pm 5 V
- Low voltage, 2.5 V CMOS/TTL compatible
- 400 MHz, 3 dB bandwidth
- Excellent isolation and crosstalk performance (typ. > 60 dB at 10 MHz)
- Fully specified from 40 °C to 85 °C and 40 °C to + 125 °C
- 14 pin TSSOP and 16 pin miniQFN package (1.8 mm x 2.6 mm)
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

- High-end data acquisition
- Medical instruments
- Precision instruments
- · High speed communications applications
- Automated test equipment
- Sample and hold applications

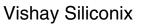
FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



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DG604





TRUTH TABLE			
Enable	Selecte	ed Input	On Switches
Input	A1	A0	DG604
L	Х	Х	All Switches Open
Н	L	L	D to S1
Н	L	Н	D to S2
Н	Н	L	D to S3
Н	Н	Н	D to S4

ORDERING INFORM	ATION	
Temp. Range	Package	Part Number
	14 pin TSSOP	DG604EQ-T1-E3
- 40 °C to 125 °C ^a	16 pin miniQFN	DG604EN-T1-E4

Notes:

a. - 40 °C to 85 °C datasheet limits apply.

ABSOLUTE MAXIMUM RAT	FINGS T _A = 25 °C, unless of	therwise noted		
Parameter		Limit	Unit	
V+ to V-		14		
GND to V-		7	v	
Digital Inputs ^a , V _S , V _D		(V-) - 0.3 to (V+) + 0.3 or 30 mA, whichever occurs first		
Continuous Current (Any Terminal)		30	mA	
Peak Current, S or D (Pulsed 1 ms, 10 %	6 Duty Cycle)	100	IIIA	
Storage Temperature		- 65 to 150	°C	
Power Dissipation (Package) ^b	14 pin TSSOP ^c	450	mW	
Fower Dissipation (Fackage)	16 pin miniQFN ^{d, e}	525	11100	
Thermal Basistance (Baskage)	14 pin TSSOP	178	C/W	
Thermal Resistance (Package) ^b	16 pin miniQFN	152	0/10	

Notes:

a. Signals on SX, DX, or INX exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.

b. All leads welded or soldered to PC board.
c. Derate 5.6 mW/°C above 70 °C.

d. Derate 6.6 mW/°C above 70 °C.

e. Manual soldering with iron is not recommended for leadless components. The miniQFN-16 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper lip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

SPECIFICATIONS	6 FOR DU	IAL SUPPLIES							
		Test Conditions Unless Otherwise Specified			- 40 °C t	o 125 °C	- 40 °C	to 85 °C	
		V+ = 5 V, V- = - 5 V							
Parameter	Symbol	V _{IN A0, A1 and ENABLE} = 2 V, 0.8 V ^a	Temp. ^b	Тур. ^с	Min. ^d	Max. ^d	Min. ^d	Max. ^d	Unit
Analog Switch									
Analog Signal Range ^e	V _{ANALOG}		Full		- 5	5	- 5	5	V
On-Resistance	R _{DS(on)}	I _S = 1 mA, V _D = - 3 V, 0 V, + 3 V	Room Full	70		115 160		115 140	
On-Resistance Match	ΔR_{ON}	$I_{S} = 1 \text{ mA}, V_{D} = \pm 3 \text{ V}$	Room Full	1		5 6.5		5 6.5	Ω
On-Resistance Flatness	R _{FLATNESS}	I _S = 1 mA, V _D = - 3 V, 0 V, + 3 V	Room Full	10		20 33		20 22	

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DG604 Vishay Siliconix

SPECIFICATIONS	FOR D	JAL SUPPLIES							
		Test Conditions Unless Otherwise Specified			- 40 °C t	o 125 °C	- 40 °C	to 85 °C	
Parameter	Symbol	V+ = 5 V, V- = - 5 V V _{IN A0, A1 and ENABLE} = 2 V, 0.8 V ^a	Temp. ^b	Typ. ^c	Min. ^d	Max. ^d	Min. ^d	Max. ^d	Unit
Analog Switch	-				•				
Switch Off	I _{S(off)}		Room	± 0.01	- 0.1	0.1	- 0.1	0.1	
Leakage Current	3(01)	V+ = 5.5 V, V- = - 5.5 V V _D = ± 4.5 V, V _S = ± 4.5 V	Full	± 0.01	- 18 - 0.1	18	- 0.5 - 0.1	0.5	
(for 14 pin TSSOP)	I _{D(off)}	VD = ± 4.0 V, VS = + 4.0 V	Room Full	± 0.01	- 18	0.1 18	- 0.1	0.1	
Channel On Leakage Current (for 14 pin TSSOP)	I _{D(on)}	V+ = 5.5 V, V- = - 5.5 V, V _S = V _D = \pm 4.5 V	Room Full	± 0.01	- 0.1 - 18	0.1 18	- 0.1 - 0.5	0.1 0.5	nA
Switch Off	I _{S(off)}	V+ = 5.5 V, V- = - 5.5 V	Room Full	± 0.01	- 1 - 18	1 18	- 1 - 2	1 2	
Leakage Current (for 16 pin miniQFN)	I _{D(off)}	$V_{\rm D} = \pm 4.5 \text{ V}, V_{\rm S} = \mp 4.5 \text{ V}$	Room Full	± 0.01	- 1 - 18	1 18	- 1 - 2	1 2	
Channel On Leakage Current (for 16 pin miniQFN)	I _{D(on)}	V + = 5.5 V, V - = -5.5 V, $V_S = V_D = \pm 4.5 V$	Room Full	± 0.01	- 1 - 18	1 18	- 1 - 2	1 2	
Digital Control		•							
Input Current, V _{IN} Low	۱ _{IL}	V _{IN A0, A1 and ENABLE} Under Test = 0.8 V	Full	0.005	- 0.1	0.1	- 0.1	0.1	μA
Input Current, V _{IN} High	I _{IH}	V _{IN A0, A1 and ENABLE} Under Test = 2 V	Full	0.005	- 0.1	0.1	- 0.1	0.1	μΛ
Input Capacitance ^e	C _{IN}	f = 1 MHz	Room	3.4					pF
Dynamic Characteristics	i	•							
Transition Time	t _{TRANS}	$\begin{split} V_{S(\text{CLOSE})} = 3 \text{ V}, \ V_{S(\text{OPEN})} = 0 \text{ V}, \\ R_L = 300 \ \Omega, \ C_L = 35 \text{ pF} \end{split}$	Room Full	20		70 105		70 80	
Turn-On Time	t _{ON}	R _L = 300 Ω, C _L = 35 pF	Room Full	16		60 90		60 65	ns
Turn-Off Time	t _{OFF}	V _S = ± 3 V	Room Full	15		52 76		52 56	115
Break-Before-Make Time Delay	t _D	V _S = 3 V R _L = 300 Ω, C _L = 35 pF	Room Full	15	10		10		
Charge Injection ^e	Q	$V_{g} = 0 V, R_{g} = 0 \Omega, C_{L} = 1 nF$	Room	0.7					рС
Off Isolation ^e	OIRR	$R_L = 50 $ Ω, $C_L = 5 $ pF, f = 10 MHz	Room	- 72					dB
Bandwidth ^e	BW	R _L = 50 Ω	Room	400					MHz
Channel-to-Channel Crosstalk ^e	X _{TALK}	R _L = 50 Ω, C _L = 5 pF, f = 10 MHz	Room	- 81					dB
Source Off Capacitance ^e	C _{S(off)}		Room	2.7					
Drain Off Capacitance ^e	C _{D(off)}	f = 1 MHz	Room	7.3					pF
Channel On Capacitance ^e	C _{D(on)}		Room	13.8					P.
Total Harmonic Distortion ^e	THD	Signal = 1 V _{RMS} , 20 Hz to 20 kHz, R _L = 600 Ω	Room	0.01					%
Power Supplies		•			•				
Power Supply Current	l+		Room Full	0.001		0.5 1		0.5 1	
Negative Supply Current	I-	$V_{IN} = 0 V$, or V+	Room Full	- 0.001	- 0.5 - 1		- 0.5 - 1		μA
Ground Current	I _{GND}		Room Full	- 0.001	- 0.5 - 1		- 0.5 - 1		

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SPECIFICATIONS FO	JR SING								1
		Test Conditions Unless Otherwise Specified V+ = 5 V, V- = 0 V			- 40 °C t	o 125 °C	- 40 °C	to 85 °C	
Parameter	Symbol	$V_{\rm IN A0, A1 and ENABLE} = 2 V, 0.8 V^{a}$	Temp. ^b	Typ. ^c	Min. ^d	Max. ^d	Min. ^d	Max. ^d	Unit
Analog Switch		•	•	•	•	•			•
Analog Signal Range ^e	V _{ANALOG}		Full			5		5	V
On-Resistance	R _{DS(on)}	I _S = 1 mA, V _D = + 3.5 V	Room Full	120		170 250		170 200	Ω
On-Resistance Match	ΔR_{ON}	$I_{\rm S}$ = 1 mA, $V_{\rm D}$ = + 3.5 V	Room Full	3		5 12		5 10	52
Switch Off Leakage Current	I _{S(off)}	V+ = 5.5 V, V- = 0 V	Room Full	± 0.01	- 0.1 - 18	0.1 18	- 0.1 - 0.5	0.1 0.5	
(for 14 pin TSSOP)	I _{D(off)}	V _D = 1 V/4.5 V, V _S = 4.5 V/1 V	Room Full	± 0.01	- 0.1 - 18	0.1 18	- 0.1 - 0.5	0.1 0.5	
Channel On Leakage Current (for 14 pin TSSOP)	I _{D(on)}	V+ = 5.5 V, V- = 0 V $V_{S} = V_{D} = 1 V/4.5 V$	Room Full	± 0.01	- 0.1 - 18	0.1 18	- 0.1 - 0.5	0.1 0.5	
Switch Off Leakage Current	I _{S(off)}	V+ = 5.5 V, V- = - 5.5 V	Room Full	± 0.01	- 1 - 18	1 18	- 1 - 2	1 2	nA
(for 16 pin miniQFN)	I _{D(off)}	V _D = 1 V/4.5 V, V _S = 4.5 V/1 V	Room Full	± 0.01	- 1 - 18	1 18	- 1 - 2	1 2	
Channel On Leakage Current (for 16 pin miniQFN)	I _{D(on)}	V+ = 5.5 V, V- = 0 V, $V_{S} = V_{D} = 1 V/4.5 V$	Room Full	± 0.01	- 1 - 18	1 18	- 1 - 2	1 2	
Digital Control			1	1	1	I			
Input Current, V _{IN} Low	١L	V _{IN A0, A1 and ENABLE} Under Test = 0.8 V	Full	0.005	- 0.1	0.1	- 0.1	0.1	
Input Current, V _{IN} High	Ι _Η	V _{IN A0, A1 and ENABLE} Under Test = 2 V	Full	0.005	- 0.1	0.1	- 0.1	0.1	μA
Input Capacitance	C _{IN}	f = 1 MHz	Room	4.3					pF
Dynamic Characteristics			•	•	•	•			•
Transition Time	t _{TRANS}		Room Full	36		75 120		75 95	
Enable Turn-On Time	t _{ON(EN)}	$V_{S(CLOSE)} = 3 \text{ V}, V_{S(OPEN)} = 0 \text{ V},$ $R_L = 300 \ \Omega, C_L = 35 \text{ pF}$	Room Full	30		70 102		70 80	ns
Enable Turn-Off Time	t _{OFF(EN)}		Room Full	17		47 88		47 63	113
Break-Before-Make-Time	t _{BMM}		Room Full	23	5		5		
Charge Injection	Q	$C_L = 1 \text{ nF}, R_{GEN} = 0 \Omega, V_{GEN} = 0 V$	Full	0.15					рС
Off-Isolation ^e	OIRR	f = 10 MHz, R _L = 50 Ω, C _L = 5 pF	Room	- 58					dB
Crosstalk ^e	X _{TALK}		Room	- 81					
Bandwidth ^e	BW	R _L = 50 Ω	Room	330					MHz
Total Harmonic Distortion	THD	Signal = 1 V _{RMS} , 20 Hz to 20 kHz, R _L = 600 Ω	Room	0.009					%
Source Off Capacitance ^e	C _{S(off)}			3.1					
Drain Off Capacitance ^e	C _{D(off)}	f = 1 MHz	Room	11.6					pF
Channel On Capacitance ^e	C _{D(on)}			16.2					
Power Supplies			•			•			
Power Supply Current	l+		Room Full	0.001		0.5 1		0.5 1	
Negative Supply Current	I-	$V_{IN} = 0 V$, or V+	Room Full	- 0.001	- 0.5 - 1		- 0.5 - 1		μA
Ground Current	I _{GND}		Room Full	- 0.001	- 0.5 - 1		- 0.5 - 1		

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SPECIFICATIONS I				1	40.00	105.00	40.00		
		Test Conditions Unless Otherwise Specified			- 40 °C to) + 125 °C	- 40 °C t	o + 85 °C	-
Parameter	Symbol	$V_{\rm H} = 3 V, V_{\rm H} = 0 V$ $V_{\rm IN A0, A1 and ENABLE} = 1.4 V, 0.6 V^{\rm a}$	Temp. ^b	Typ. ^c	Min. ^d	Max. ^d	Min. ^d	Max. ^d	Uni
Analog Switch	•,	TIN AU, AT ANU ENABLE		.,,					
Analog Signal Range ^e	V _{ANALOG}		Full			3		3	v
			Room	200		245		245	-
On-Resistance	R _{DS(ON)}	$I_{\rm S}$ = 1 mA, $V_{\rm D}$ = + 1.5 V	Full			325		290	Ω
On-Resistance Match	ΔR_{ON}	I _S = 1 mA, V _D = + 1.5 V	Room Full	5		6 13		11 6	52
Switch Off	I _{S(off)}	V+ = 3 V, V- = 0 V	Room Full	± 0.01	- 0.1 - 18	0.1 18	- 0.1 - 0.5	0.1 0.5	
Leakage Current (for 14 pin TSSOP)	I _{D(off)}	V _D = 1 V/3 V, V _S = 3 V/1 V	Room Full	± 0.01	- 0.1 - 18	0.1 18	- 0.1 - 0.5	0.1 0.5	
Channel On Leakage Current (for 14 pin TSSOP)	I _{D(on)}	V+ = 3 V, V- = 0 V V _S = V _D = 1 V/3 V	Room Full	± 0.01	- 0.1 - 18	0.1 18	- 0.1 - 0.5	0.1 0.5	
Switch Off	I _{S(off)}	V+ = 3.3 V. V- = 0 V	Room Full	± 0.01	- 1 - 18	1 18	- 1 - 2	1 2	nA
Leakage Current (for 16 pin miniQFN)	I _{D(off)}	$V_{\rm D} = 1 \text{ V/3 V}, V_{\rm S} = 3 \text{ V/1 V}$	Room	± 0.01	- 1 - 18	1 18	- 1 - 2	1 2	
Channel On Leakage Current (for 16 pin miniQFN)	I _{D(on)}	V+ = 3.3 V, V- = 0 V V _D = 1 V/3 V, V _S = 3 V/1 V	Room Full	± 0.01	- 1 - 18	1 18	- 1 - 2	1 2	-
Digital Control	L						L		1
Input Current, V _{IN} Low	ΙL	V _{IN A0, A1 and ENABLE} Under Test = 0.6 V	Full	0.005	- 1	1	- 1	1	
Input Current, V _{IN} High	Ι _Η	V _{IN A0, A1 and ENABLE} Under Test = 1.4 V	Full	0.005	- 1	1	- 1	1	- μΑ
Input Capacitance	C _{IN}	f = 1 MHz	Room	4.3					pF
Dynamic Characteristics						I			<u> </u>
Transition Time	trouvo		Room	95		130		130	
	t _{TRANS}		Full			190		160	
Enable Turn-On Time	t _{ON(EN)}	$V_{S(CLOSE)} = 3 \text{ V}, V_{S(OPEN)} = 0 \text{ V},$ $R_{L} = 300 \Omega, C_{L} = 35 \text{ pF}$	Room Full	77		108 161		108 131	ns
Enable Turn-Off Time	t _{OFF(EN)}		Room Full	35		76 112		76 88	
Break-Before-Make-Time	t _{BMM}		Room Full	45	5		5		
Charge Injection	Q	C _L = 1 nF, R _{GEN} = 0 Ω, V _{GEN} = 0 V	Full	0.1	5		5		pC
Off-Isolation ^e	OIRR		Room	- 58					pe
Crosstalk ^e	X _{TALK}	f = 10 MHz, $R_L = 50 \Omega$, $C_L = 5 pF$	Room	- 90					dB
Bandwidth ^e	BW	R _L = 50 Ω	Room	290					МН
Total Harmonic Distortion	THD	Signal = 1 V _{RMS,} 20 Hz to 20 kHz,	Room	0.09					%
Source Off Capacitance ^e	C _{S(off)}	R _L = 600 Ω		3.1					
Drain Off Capacitance ^e	. ,	f = 1 MHz	Room	3.1 11.7					~
Channel On Capacitance ^e	C _{D(off)}								pF
Power Supplies	C _{D(on)}			16.5				I	
			Room	0.001		0.5		0.5	
Power Supply Current	l+		Full			1		1	
Negative Supply Current	l-	$V_{IN} = 0 V$, or V+	Room Full	- 0.001	- 0.5 - 1		- 0.5 - 1		μA
Ground Current	I _{GND}		Room Full	- 0.001	- 0.5 - 1		- 0.5 - 1		1

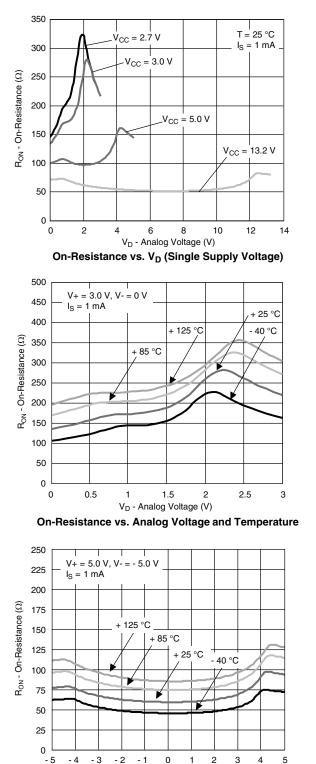
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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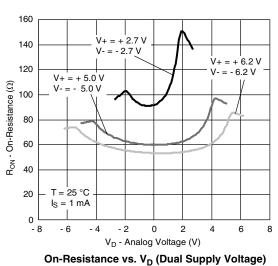
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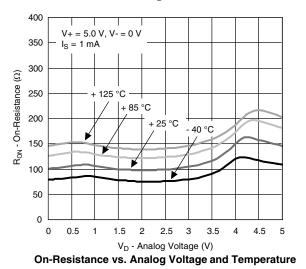


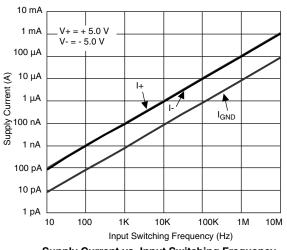
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



V_D - Analog Voltage (V) On-Resistance vs. Analog Voltage and Temperature





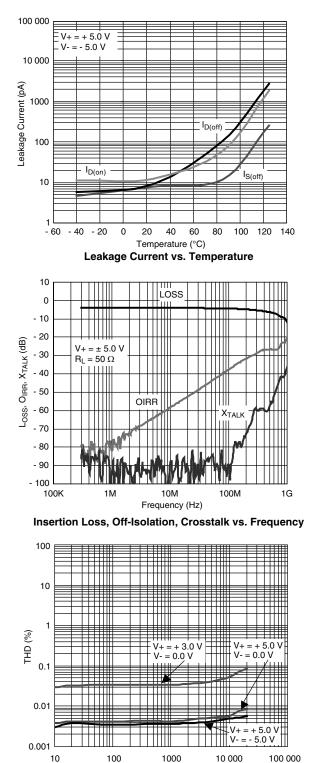


Supply Current vs. Input Switching Frequency

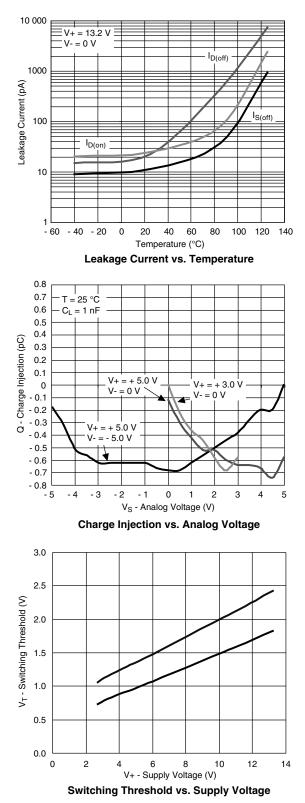
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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Frequency (Hz)
Total Harmonic Distortion vs. Frequency



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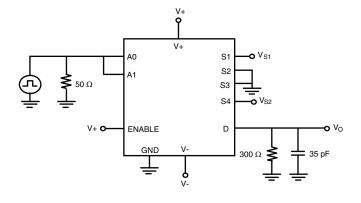
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TEST CIRCUITS



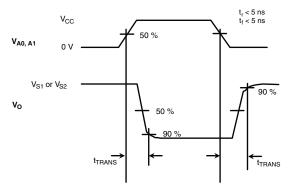
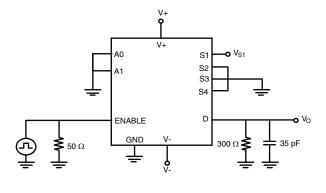


Figure 1. Transition Time



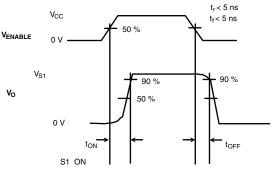
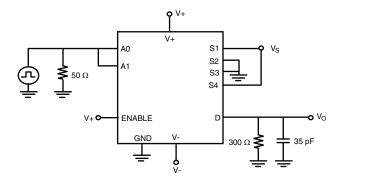


Figure 2. Enable Switching Time



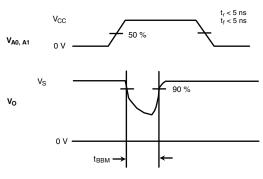
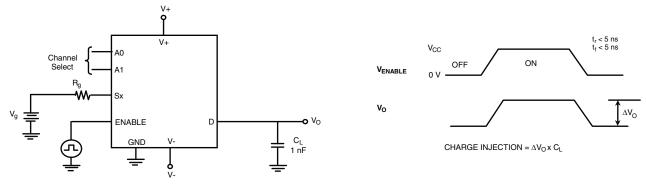


Figure 3. Break-Before-Make

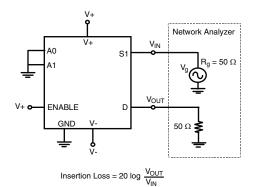


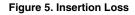
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TEST CIRCUITS









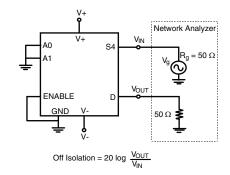


Figure 6. Off-Isolation

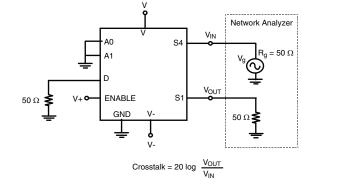


Figure 7. Crosstalk

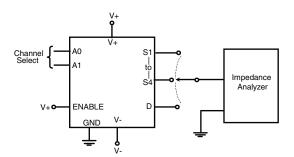


Figure 8. Source/Drain Capacitance

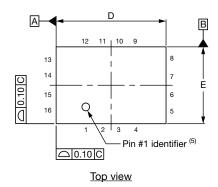
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg269934.

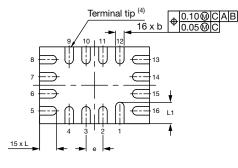
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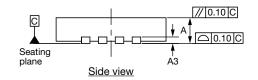
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Thin miniQFN16 Case Outline





Bottom view



DIMENSIONS		MILLIMETERS (1)			INCHES		
DIMENSIONS	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
А	0.50	0.55	0.60	0.020	0.022	0.024	
A1	0	-	0.05	0	-	0.002	
A3		0.15 ref.			0.006 ref.		
b	0.15	0.20	0.25	0.006	0.008	0.010	
D	2.50	2.60	2.70	0.098	0.102	0.106	
е		0.40 BSC		0.016 BSC			
E	1.70	1.80	1.90	0.067	0.071	0.075	
L	0.35	0.40	0.45	0.014	0.016	0.018	
L1	0.45	0.50	0.55	0.018	0.020	0.022	
N ⁽³⁾		16			16		
Nd ⁽³⁾		4			4		
Ne ⁽³⁾		4			4		

Notes

⁽¹⁾ Use millimeters as the primary measurement.

- ⁽²⁾ Dimensioning and tolerances conform to ASME Y14.5M. 1994.
- ⁽³⁾ N is the number of terminals. Nd and Ne is the number of terminals in each D and E site respectively.

 $^{(4)}$ Dimensions b applies to plated terminal and is measured between 0.15 mm and 0.30 mm from terminal tip.

⁽⁵⁾ The pin 1 identifier must be existed on the top surface of the package by using identification mark or other feature of package body.

⁽⁶⁾ Package warpage max. 0.05 mm.

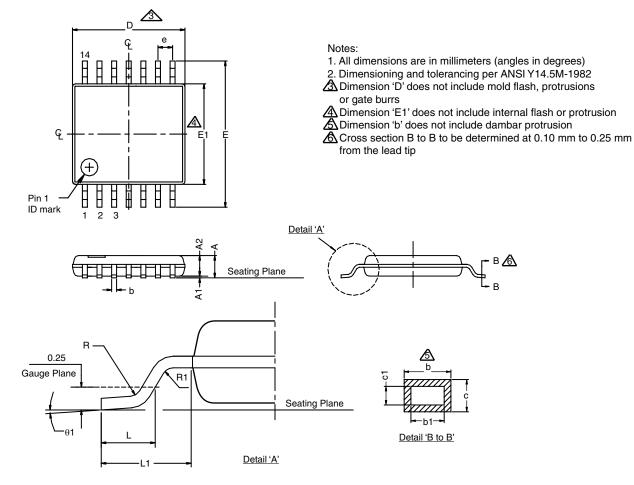
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Package Information

Vishay Siliconix

14L TSSOP



SYMBOL	MINIMUM	NOMINAL	MAXIMUM	
Α	-	-	1.20	
A1	0.05	- 0.15		
A2	0.80	0.90	1.05	
D	4.9	5.0	5.1	
E1	4.3	4.4	4.5	
E	6.2	6.4	6.6	
L	0.45	0.60	0.75	
R	0.09	-	-	
R1	0.09	-	-	
b	0.19	-	0.30	
b1	0.19	0.22	0.25	
С	0.09	-	0.20	
c1	0.09	-	0.16	
θ1	0°	-	8°	
L1		1.0 ref.		
е		0.65 BSC		



Vishay

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